

#### Description

The 20P03-HXY uses advanced trench technology

to provide excellent  $R_{\text{DS}(\text{ON})},$  low gate charge and

operation with gate voltages as low as 4.5V. This

device is suitable for use as a

Battery protection or in other Switching application.

#### **General Features**

V<sub>DS</sub> = -30V I<sub>D</sub> =-20A

 $R_{DS(ON)} < 42 \text{ m}\Omega @ V_{GS} = 10V$ 

#### Application

Battery protection

Load switch

Uninterruptible power supply

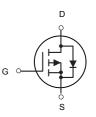
#### Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
20P03-HXY	TO252-2L	20P03 XXX YYYY	2500

#### Absolute Maximum Ratings (Tc=25°C unless otherwise noted)

Symbol	Parameter	eter Rating	
VDS	Drain-Source Voltage	rce Voltage -30	
VGS	Gate-Source Voltage	±25	V
I⊳@Tc=25°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	ntinuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> -20	
I₀@Tc=100°C	Continuous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup>	ous Drain Current, V <sub>GS</sub> @ 10V <sup>1</sup> -15	
IDM	Pulsed Drain Current <sup>2</sup>	Pulsed Drain Current <sup>2</sup> -50	
P₀@Tc=25°C	Total Power Dissipation <sup>4</sup>	29	W
TSTG	Storage Temperature Range	-55 to 150	°C
TJ	Operating Junction Temperature Range	-55 to 150	°C
R₀JA	Thermal Resistance Junction-ambient <sup>1</sup>	75	°C/W
R₀JC	Thermal Resistance Junction-Case <sup>1</sup>	4.32	°C/W





P-Channel MOSFET



### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тр	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	VGS=0V , ID=-250uA	-30			V
∆BVDSS/∆TJ	BVDSS Temperature Coefficient	Reference to 25℃ , ID=-1mA		22		V/°C
RDS(ON)	Static Drain-Source On-Resistance2	VGS=-10V , ID=-15A	32	38	42	mΩ
		VGS=-4.5V , ID=-10A	48	60	70	
VGS(th)	Gate Threshold Voltage	VGS=VDS , ID =-250uA	-1.0		-2.5	V
∆VGS(th)	VGS(th) Temperature Coefficient			4.6		mV/°C
		VDS=-24V, VGS=0V,	1		-1	
		TJ=25℃				
	Drain-Source Leakage Current	VDS=-24V , VGS=0V ,			-5	uA
		TJ=55℃				
IGSS	Gate-Source LeakageCurrent	VGS=±25V , VDS=0V			±100	nA
gfs	Forward Transconductance	VDS=-5V , ID=-15A		19		S
Rg	Gate Resistance	VDS=0V , VGS=0V , f=1MHz		13		
Qg	Total Gate Charge (-4.5V)			12.5		
Qgs	Gate-Source Charge	VDS=-15V , VGS=-4.5V , ID=-15A		5.4		nC
Qgd	Gate-Drain Charge	-		5		
Td(on)	Turn-On Delay Time	VDD=-15V , VGS=-10V , RG=3.3 , ID=-15A		4.4		ns
Tr	Rise Time			11.2		
Td(off)	Turn-Off Delay Time			34		
Tf	Fall Time			18		
Ciss	Input Capacitance	 VDS=-15V , VGS=0V , f=1MHz		1345		pF
Coss	Output Capacitance			194		
Crss	Reverse Transfer Capacitance			158		

#### Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.

**2.** Surface Mounted on FR4 Board,  $t \le 10$  sec.

**3.** Pulse Test: Pulse Width  $\leq$  300µs, Duty Cycle  $\leq$  2%.

4. Guaranteed by design, not subject to production

V<sub>GS</sub>=-4.5V I<sub>D</sub>=-15A

125

150

175

V<sub>GS</sub>=-10V I<sub>D</sub>=-15A

50

Coss

125

0.2

0.4

10

15

20

25°

0.8

0.6

25

30

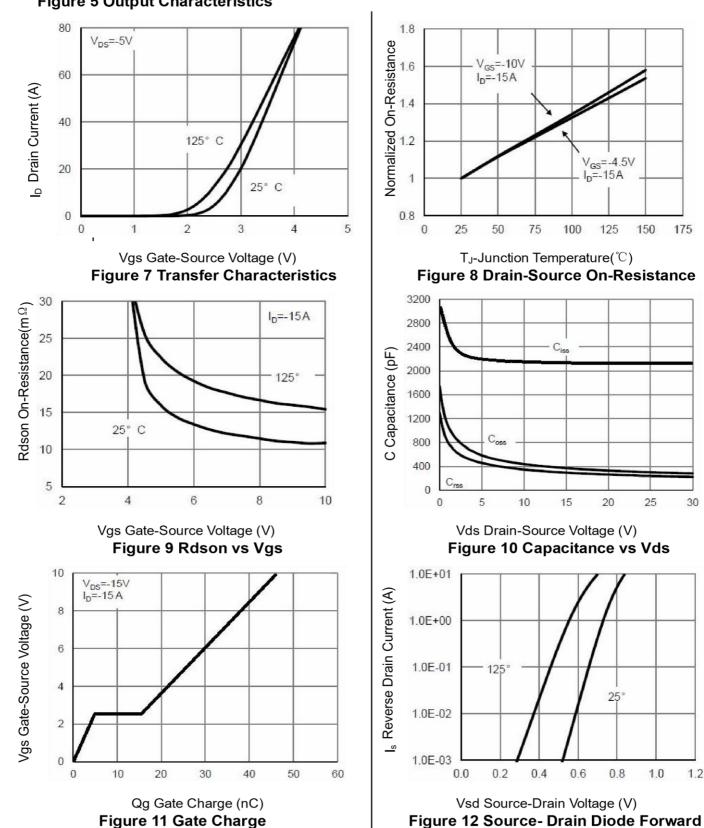
5

75

100



## **Typical Electrical and Thermal Characteristics**



## **Figure 5 Output Characteristics**

1.0

1.2



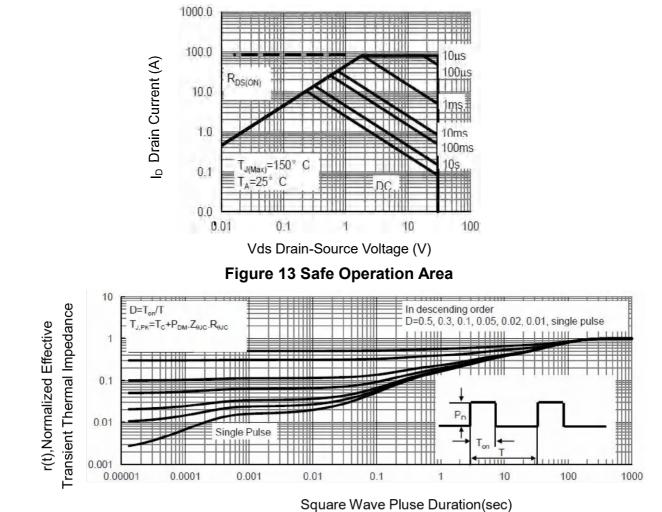
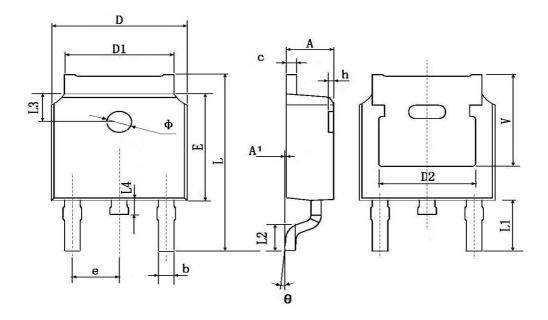


Figure 14 Normalized Maximum Transient Thermal Impedance



# TO252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
e	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.60	0 TYP.	0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Φ	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.35	5.350 TYP. 0.211 TYP.		TYP.	



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